

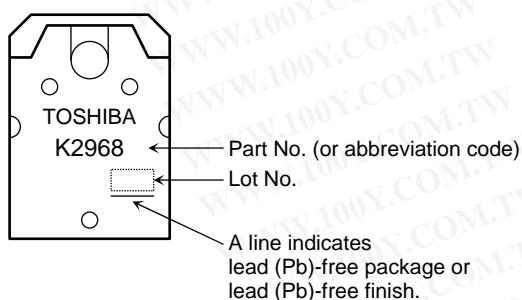
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = \pm 30\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 10	μA
Gate-source breakdown voltage		$V_{(BR)GSS}$	$I_G = \pm 10\ \mu\text{A}, V_{DS} = 0\text{ V}$	± 30	—	—	V
Drain cut-off current		I_{DSS}	$V_{DS} = 720\text{ V}, V_{GS} = 0\text{ V}$	—	—	100	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	900	—	—	V
Gate threshold voltage		V_{th}	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	2.0	—	4.0	V
Drain-source ON resistance		$R_{DS(ON)}$	$V_{GS} = 10\text{ V}, I_D = 4\text{ A}$	—	1.05	1.25	Ω
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 15\text{ V}, I_D = 4\text{ A}$	3.5	7.6	—	S
Input capacitance		C_{iss}	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	2150	—	pF
Reverse transfer capacitance		C_{rss}		—	35	—	
Output capacitance		C_{oss}		—	220	—	
Switching time	Rise time	t_r		—	25	—	ns
	Turn-on time	t_{on}		—	60	—	
	Fall time	t_f		—	25	—	
	Turn-off time	t_{off}		—	120	—	
Total gate charge (gate-source plus gate-drain)		Q_g	$V_{DD} \approx 400\text{ V}, V_{GS} = 10\text{ V}, I_D = 10\text{ A}$	—	70	—	nC
Gate-source charge		Q_{gs}		—	37	—	
Gate-drain ("miller") Charge		Q_{gd}		—	33	—	

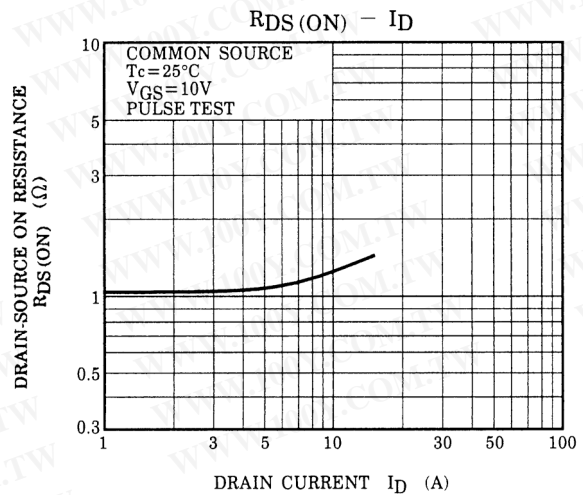
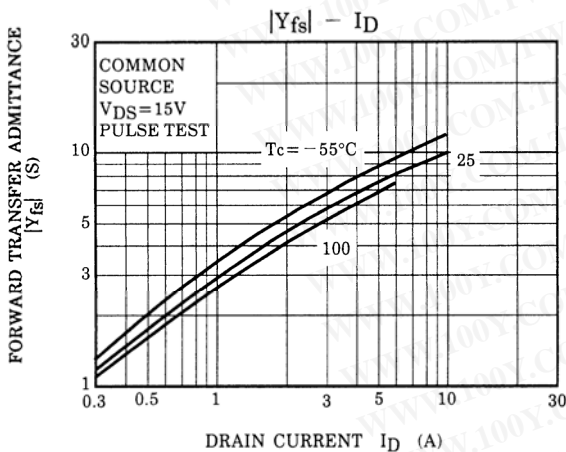
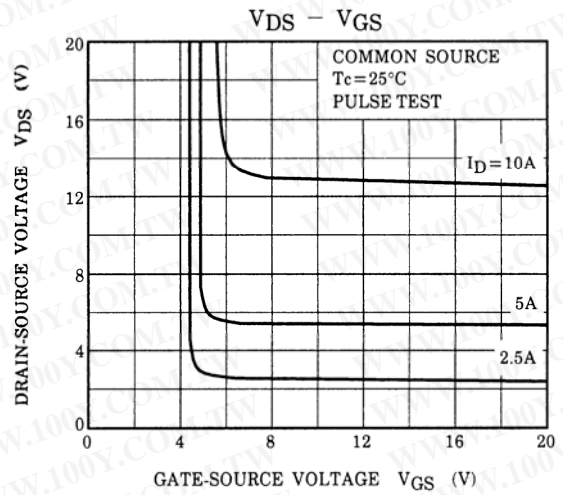
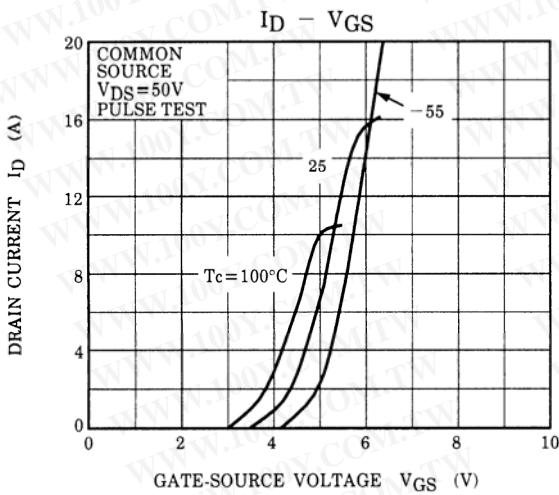
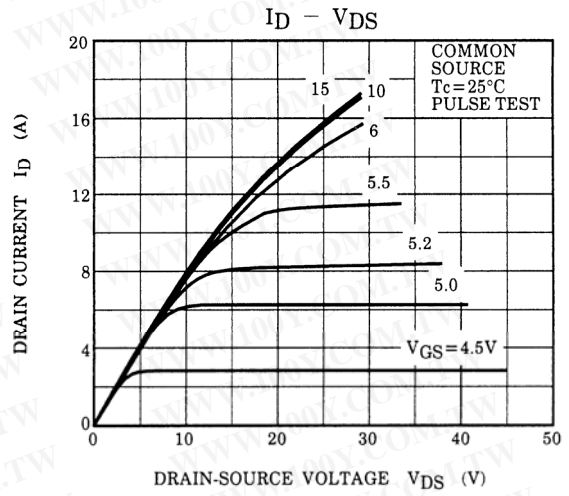
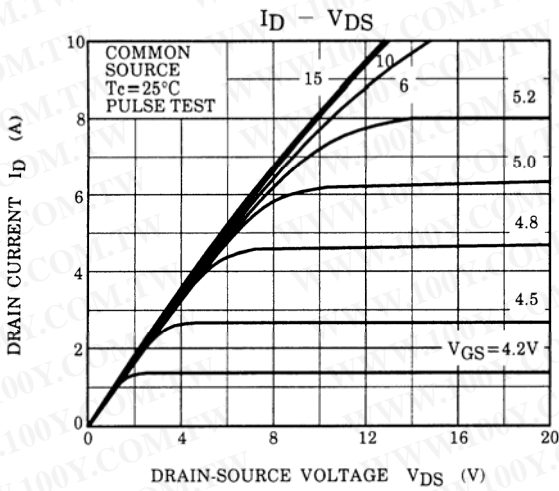
Source-Drain Ratings and Characteristics (Ta = 25°C)

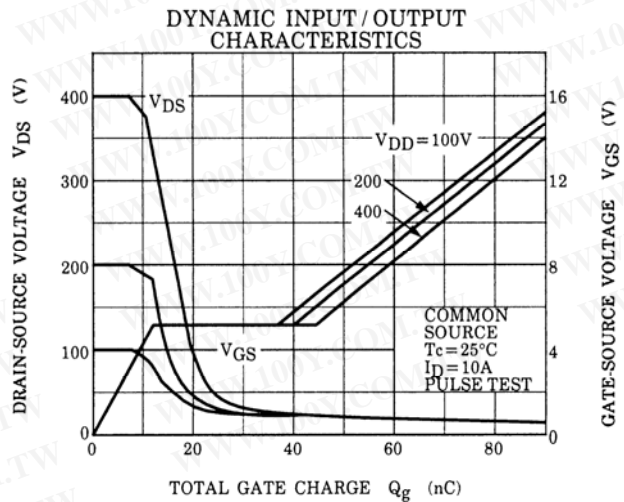
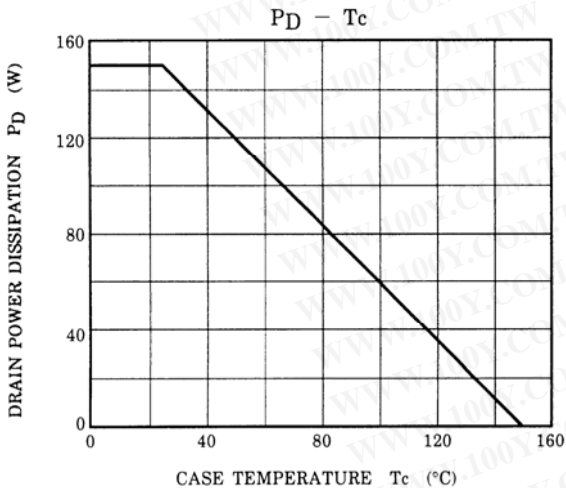
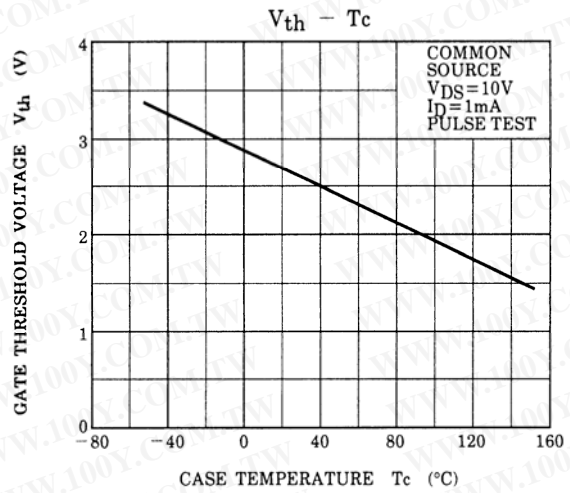
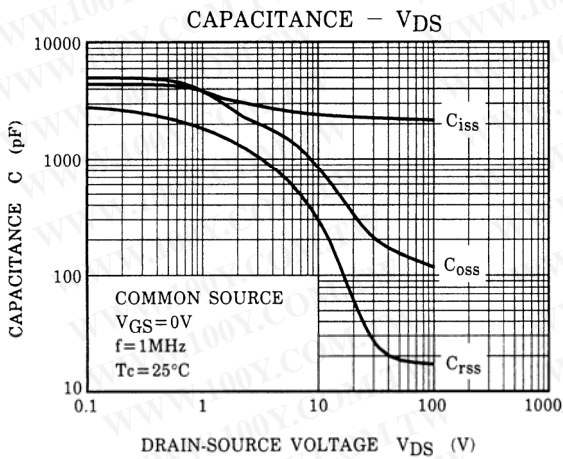
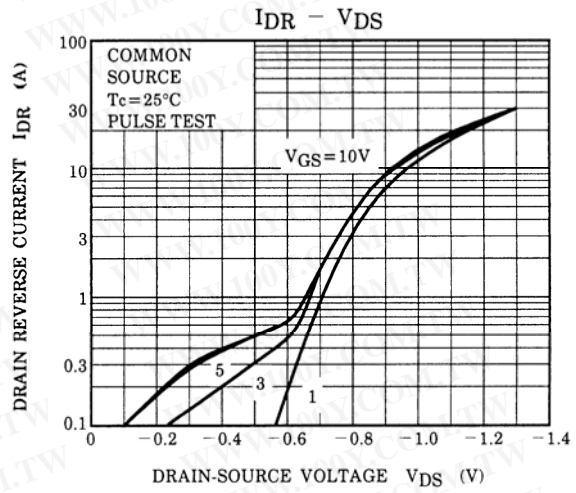
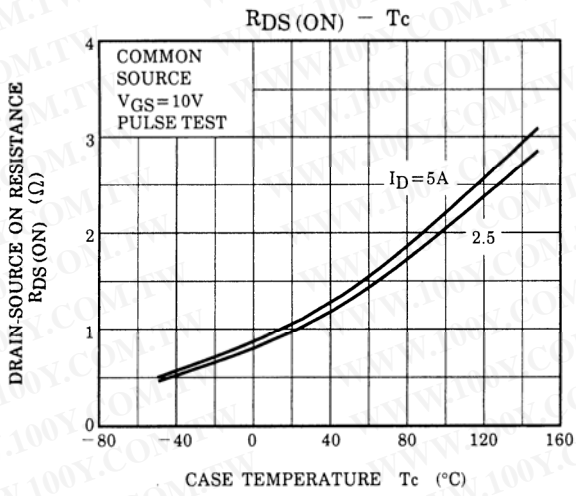
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	—	—	—	10	A
Pulse drain reverse current (Note 1)	I_{DRP}	—	—	—	30	A
Forward voltage (diode)	V_{DSF}	$I_{DR} = 10\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.9	V
Reverse recovery time	t_{rr}	$I_{DR} = 10\text{ A}, V_{GS} = 0\text{ V}$	—	1300	—	ns
Reverse recovery charge	Q_{rr}	$dI_{DR} / dt = 100\text{ A} / \mu\text{s}$	—	14.5	—	μC

Marking

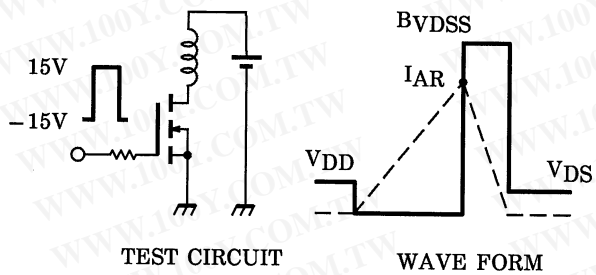
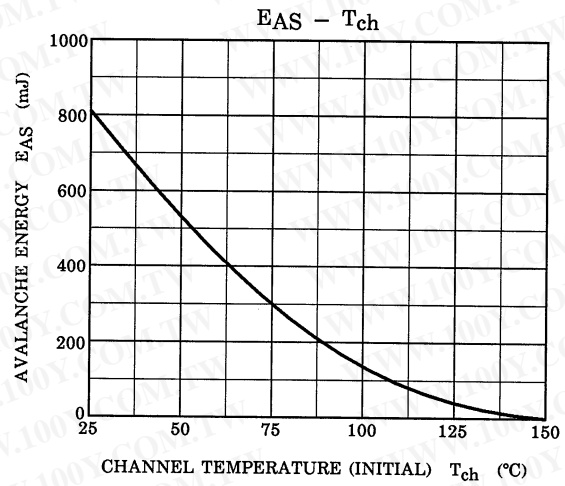
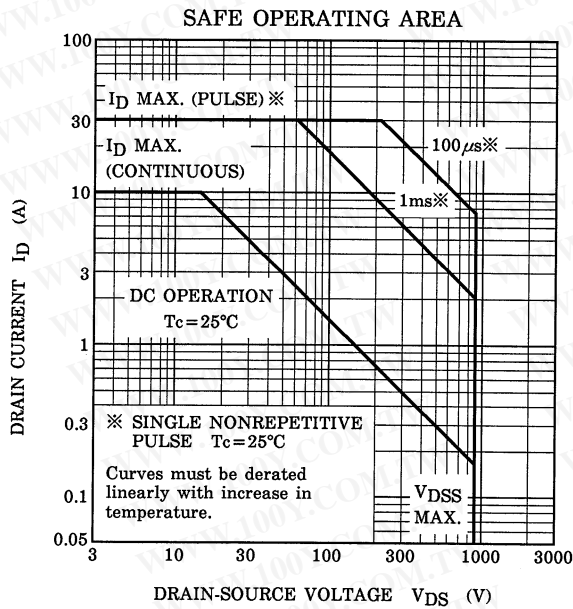
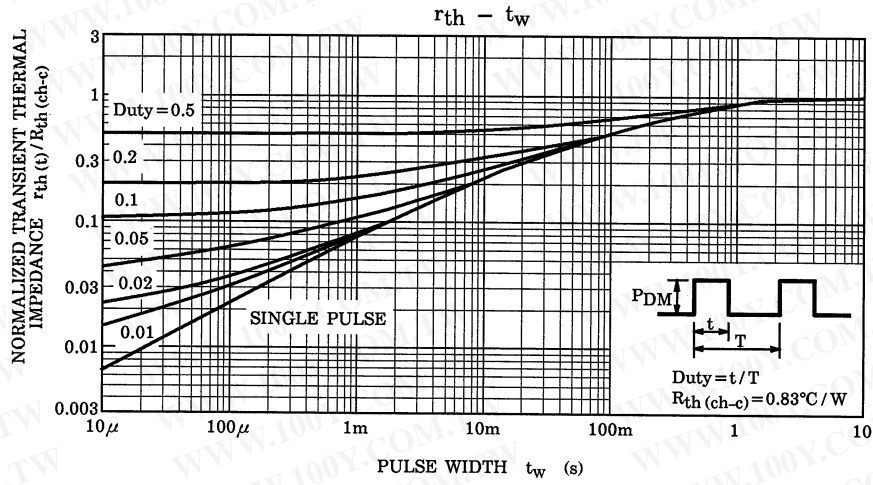


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$R_G = 25 \Omega$
 $V_{DD} = 90 \text{ V}, L = 14.9 \text{ mH}$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - V_{DD}} \right)$$

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